

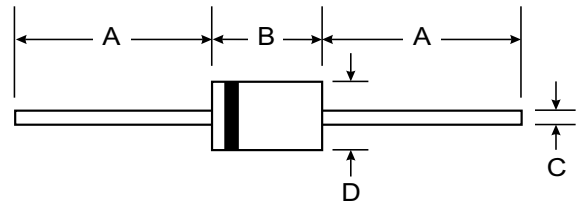
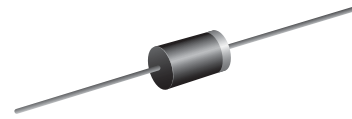
**VOLTAGE RANGE: 50 - 1000V**  
**CURRENT: 2.0 A**

### Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

### Mechanical Data

- Case: DO-15, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.40 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



DO-15		
Dim	Min	Max
A	25.40	—
B	5.50	7.62
C	0.686	0.889
D	2.60	3.60
All Dimensions in mm		

### Maximum Ratings and Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	EGP 20A	EGP 20B	EGP 20D	EGP 20F	EGP 20G	EGP 20J	EGP 20K	EGP 20M	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	200	300	400	600	800	1000	V	
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	140	210	280	420	560	700	V	
Average Rectified Output Current (Note 1) @T <sub>A</sub> = 55°C	I <sub>O</sub>	2.0								A	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	60								A	
Forward Voltage @I <sub>F</sub> = 2.0A	V <sub>FM</sub>	1.0			1.3		1.7			V	
Peak Reverse Current @T <sub>A</sub> = 25°C At Rated DC Blocking Voltage @T <sub>A</sub> = 100°C	I <sub>RM</sub>	5.0 100								μA	
Reverse Recovery Time (Note 2)	t <sub>rr</sub>	50					75				nS
Typical Junction Capacitance (Note 3)	C <sub>j</sub>	60					40				pF
Operating Temperature Range	T <sub>j</sub>	-65 to +125								°C	
Storage Temperature Range	T <sub>STG</sub>	-65 to +150								°C	

## RATINGS AND CHARACTERISTIC CURVES EGP20A THRU EGP20M

